

**Amplifier, Power, 0.5W
12.7-15.4 GHz**

MAAP-000044-PKG003
Rev A
Preliminary Datasheet

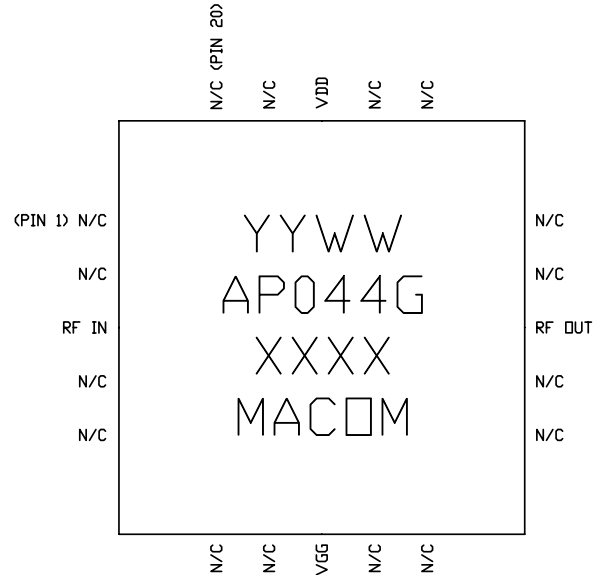
Features

- ◆ 0.5 Watt Saturated Output Power Level
- ◆ Variable Drain Voltage (6-10V) Operation
- ◆ MSAG™ Process
- ◆ 5x5 mm 20 Lead MLP Package

Description

The MAAP-000044-PKG0003 is a 3-stage 0.5 W power amplifier with on-chip bias networks in a 20 lead MLP package, allowing easy assembly. This product is fully matched to 50 ohms on both the input and output. It can be used as a power amplifier stage or as a driver stage in high power applications.

Each device is 100% RF tested to ensure performance compliance. The part is fabricated using M/A-COM's GaAs Multifunction Self-Aligned Gate (MSAG™) Process.



Primary Applications

- ◆ **Point-to-Point Radio**
 - ◇ 13 and 15 GHz Bands
- ◆ **SatCom**
- ◆ **Radio Communications**

Also Available in:

| | | SAMPLE BOARD |
|-------------|----------------|--------------------|
| Description | Die | Plastic Package |
| Part Number | MAAPGM0044-DIE | MAAP-000044-SMB003 |

Electrical Characteristics: $T_C = 30^\circ C^1$, $Z_0 = 50\Omega$, $V_{DD} = 8V$, $I_{DQ} = 210 mA^2$, $P_{in} = 14dBm$, $R_G = 350\Omega$

| Parameter | Symbol | Typical | Units |
|--|-----------|-----------|-------|
| Bandwidth | f | 12.7-15.4 | GHz |
| Output Power | P_{OUT} | 27 | dBm |
| Power Added Efficiency | PAE | 22 | % |
| 1-dB Compression Point | P_{1dB} | 26 | dBm |
| Small Signal Gain | G | 17 | dB |
| Input VSWR | VSWR | 2.5:1 | — |
| Output VSWR | VSWR | 2.2:1 | — |
| Gate Supply Current | I_{GG} | < 2 | mA |
| Drain Supply Current | I_{DD} | < 0.4 | A |
| Output Third Order Intercept | OTOI | 34 | dBm |
| 3 rd Order Intermodulation Distortion, Single Carrier Level = 16 dBm | IM3 | -20 | dBm |

1. T_C = Case Temperature.
2. Adjust V_{GG} between -2.6 to -1.2 to achieve indicated I_{DQ} .

M/A-COM Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. M/A-COM makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does M/A-COM assume any liability whatsoever arising out of the use or application of any product(s) or information.

- **North America** Tel: 800.366.2266 / Fax: 978.366.2266
- **Europe** Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- **Asia/Pacific** Tel: 81.44.844.8296 / Fax: 81.44.844.8298

Visit www.macom.com for additional data sheets and product information.

**Amplifier, Power, 0.5W
12.7-15.4 GHz**

MAAP-000044-PKG003
Rev A
Preliminary Datasheet

Maximum Ratings³

| Parameter | Symbol | Absolute Maximum | Units |
|---------------------------------------|------------|------------------|-------|
| Input Power | P_{IN} | 19.0 | dBm |
| Drain Supply Voltage | V_{DD} | +12.0 | V |
| Gate Supply Voltage | V_{GG} | -3.0 | V |
| Quiescent Drain Current (No RF) | I_{DQ} | 340 | mA |
| Quiescent DC Power Dissipated (No RF) | P_{DISS} | 3.4 | W |
| Junction Temperature | T_J | 170 | °C |
| Storage Temperature | T_{STG} | -55 to +150 | °C |

3. Operation beyond these limits may result in permanent damage to the part.

Recommended Operating Conditions⁴

| Characteristic | Symbol | Min | Typ | Max | Unit |
|--------------------------|---------------|------|------|--------|------|
| Drain Supply Voltage | V_{DD} | 6.0 | 8.0 | 10.0 | V |
| Gate Supply Voltage | V_{GG} | -2.6 | -1.7 | -1.2 | V |
| Input Power | P_{IN} | | 14.0 | 17.0 | dBm |
| Junction Temperature | T_J | | | 150 | °C |
| Thermal Resistance | Θ_{JC} | | 33.4 | | °C/W |
| Package Base Temperature | T_B | | | Note 5 | °C |

4. Operation outside of these ranges may reduce product reliability.

5. Maximum Package Case Temperature = 170°C — $\Theta_{JC} * V_{DD} * I_{DQ}$

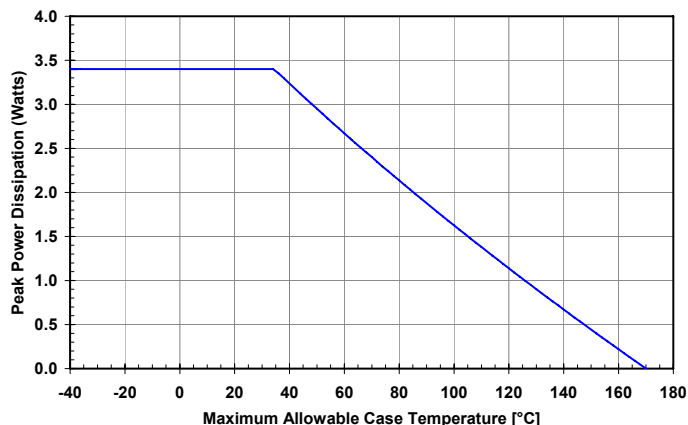


Operating Instructions

This device is static sensitive. Please handle with care. To operate the device, follow these steps.

1. Apply $V_{GG} = -1.7$ V, $V_{DD} = 0$ V.
2. Ramp V_{DD} to desired voltage, typically 8 V.
3. Adjust V_{GG} to set I_{DQ} , (approximately @ -1.7V).
4. Set RF input.
5. Power down sequence in reverse. Turn gate voltage off last.

Power Derating Curve, Quiescent (No RF)



**Amplifier, Power, 0.5W
12.7-15.4 GHz**

MAAP-000044-PKG003
Rev A
Preliminary Datasheet

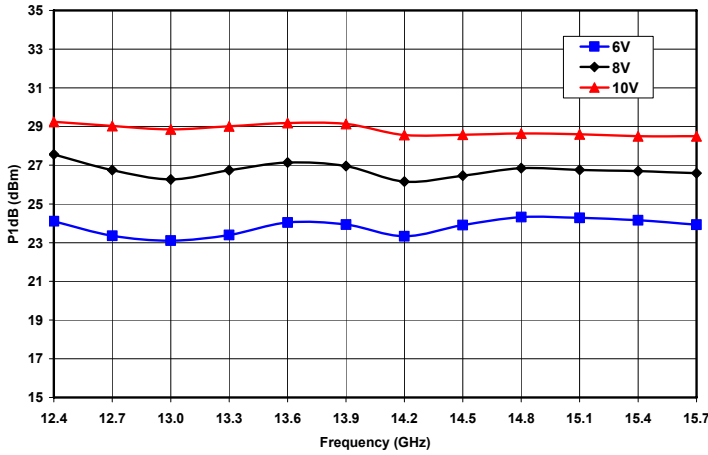


Figure 1. 1 dB Compression Point vs. Frequency and Drain Voltage at IDQ = 210mA

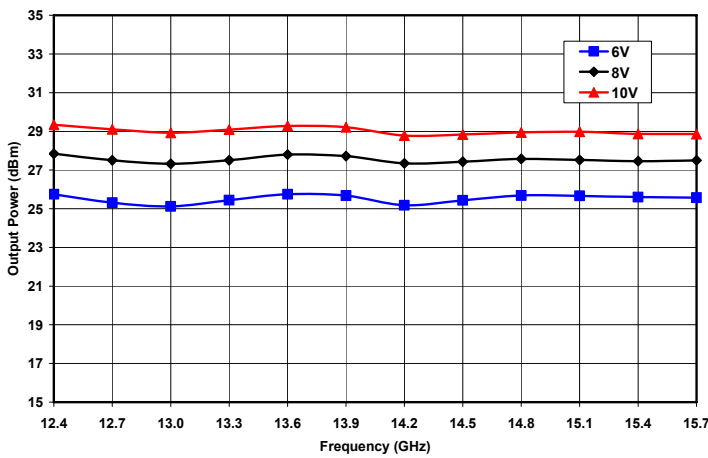


Figure 3. Saturated Output Power vs. Frequency and Drain Voltage at IDQ = 210mA

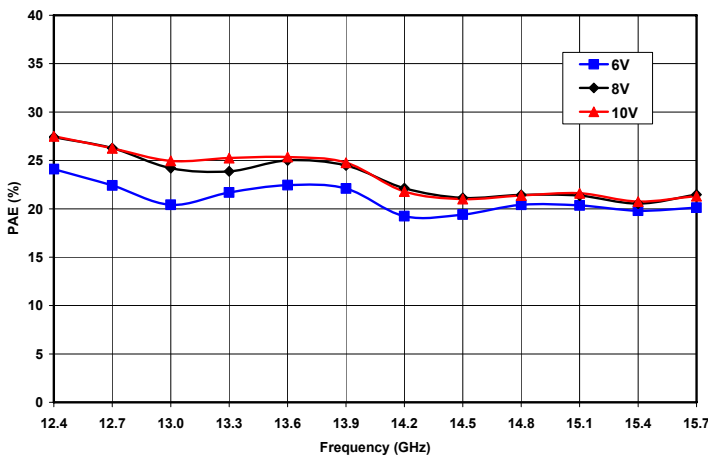


Figure 5. Saturated Power Added Efficiency vs. Frequency and Drain Voltage at IDQ = 210mA

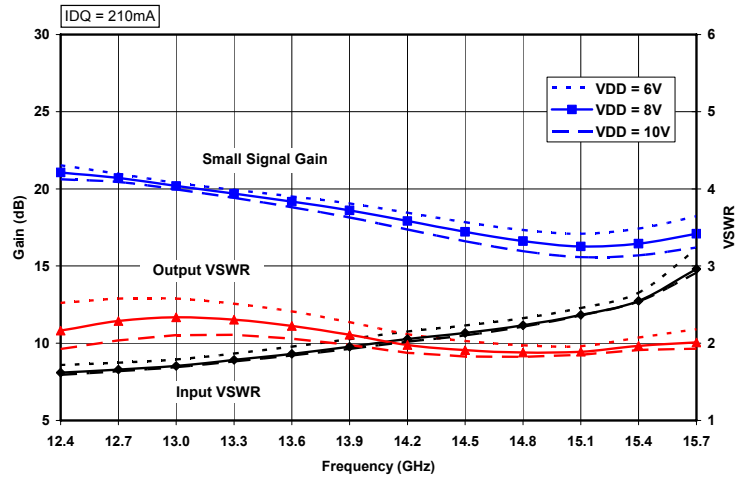


Figure 2. Small Signal Gain and Input & Output VSWR vs. Frequency and Drain Voltage at IDQ = 210mA

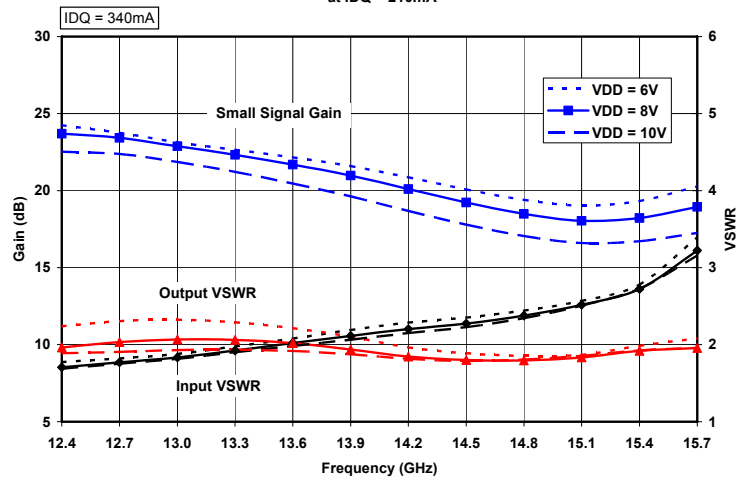


Figure 4. Small Signal Gain and Input & Output VSWR vs. Frequency and Drain Voltage at IDQ = 340mA

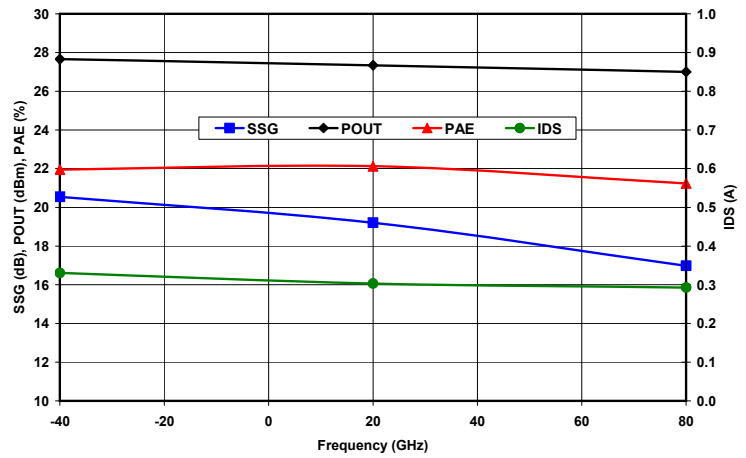


Figure 6. Small Signal Gain & Saturated Output Power, Power Added Efficiency and Drain Current vs. Case Temperature at 14.2 GHz, VD = 8V and IDQ = 210mA

M/A-COM Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. M/A-COM makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does M/A-COM assume any liability whatsoever arising out of the use or application of any product(s) or information.

- **North America** Tel: 800.366.2266 / Fax: 978.366.2266
- **Europe** Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- **Asia/Pacific** Tel: 81.44.844.8296 / Fax: 81.44.844.8298

Visit www.macom.com for additional data sheets and product information.

**Amplifier, Power, 0.5W
12.7-15.4 GHz**

MAAP-000044-PKG003
Rev A
Preliminary Datasheet

VD = 6V

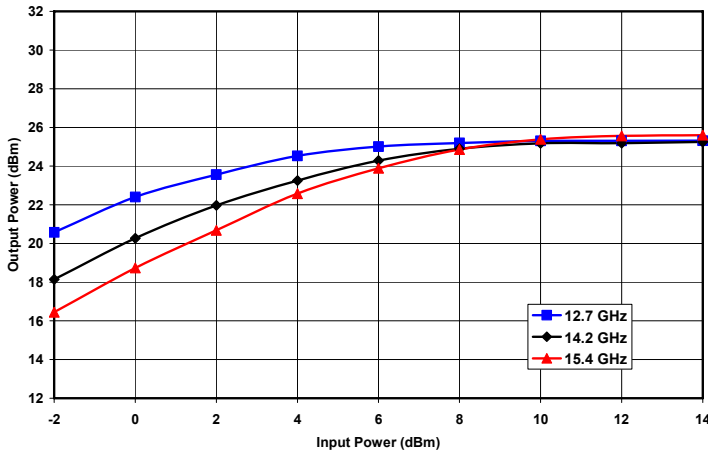


Figure 7. Output Power vs. Input Power and Frequency at VD = 6V and IDQ = 210mA

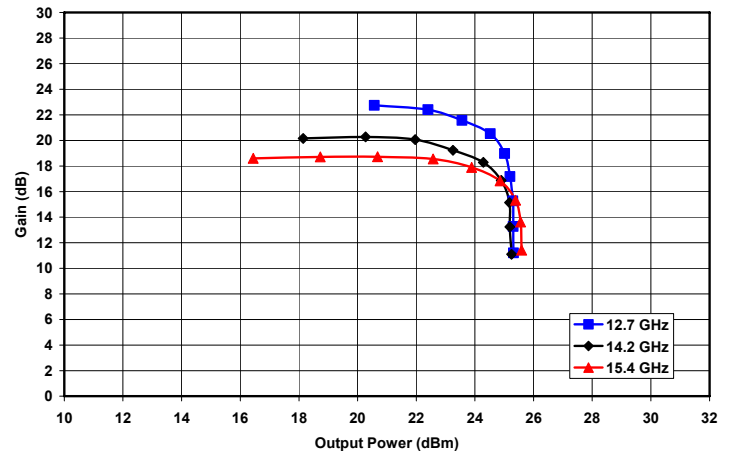


Figure 8. Gain vs. Output Power and Frequency at VD = 6V and IDQ = 210mA

VD = 8V

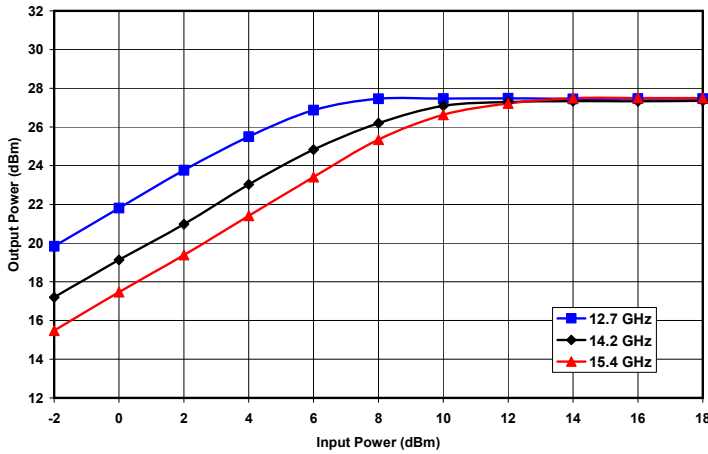


Figure 9. Output Power vs. Input Power and Frequency at VD = 8V and IDQ = 210mA

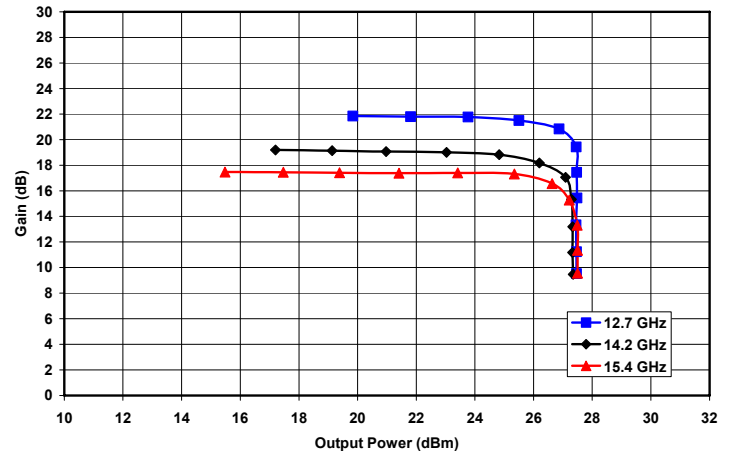


Figure 10. Gain vs. Output Power and Frequency at VD = 8V and IDQ = 210mA

VD = 10V

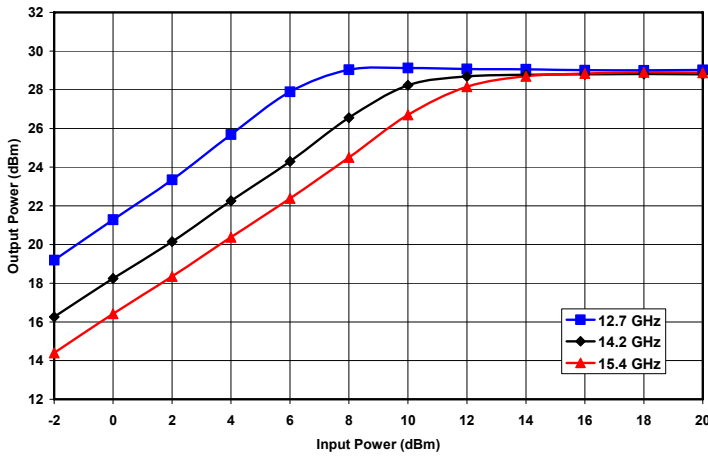


Figure 11. Output Power vs. Input Power and Frequency at VD = 10V and IDQ = 210mA

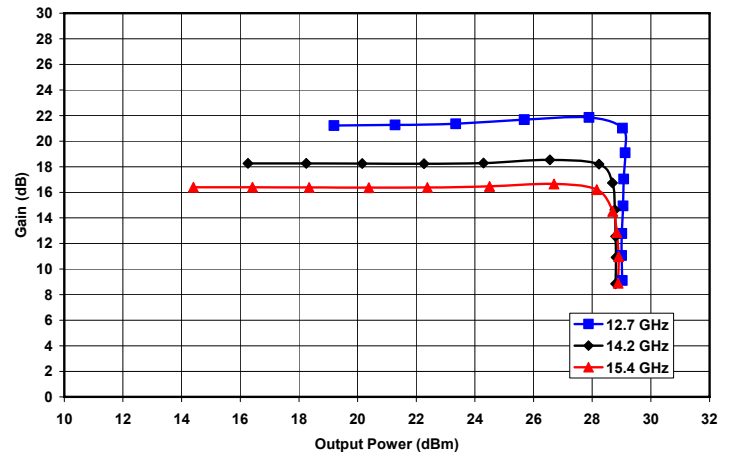


Figure 12. Gain vs. Output Power and Frequency at VD = 10V and IDQ = 210mA

**Amplifier, Power, 0.5W
12.7-15.4 GHz**

MAAP-000044-PKG003
Rev A
Preliminary Datasheet

VD = 6V

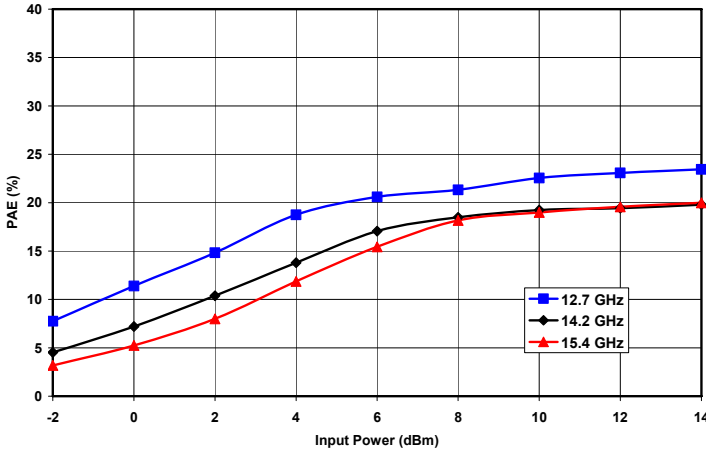


Figure 13. Power Added Efficiency vs. Input Power and Frequency at VD = 6V and IDQ = 210mA

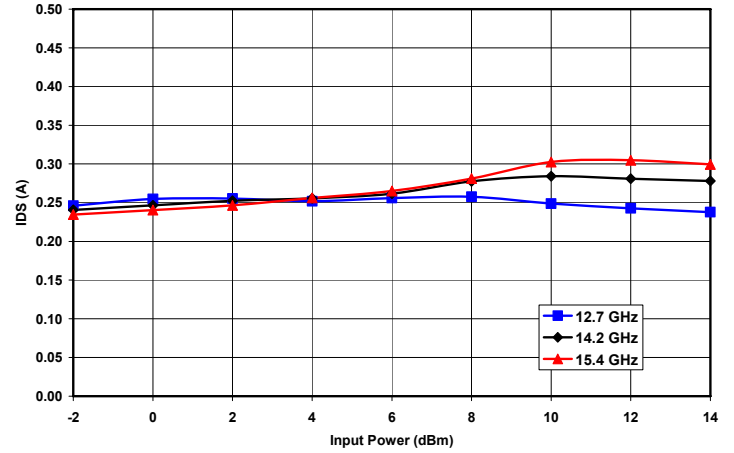


Figure 14. Drain Current vs. Input Power and Frequency at VD = 6V and IDQ = 210mA

VD = 8V

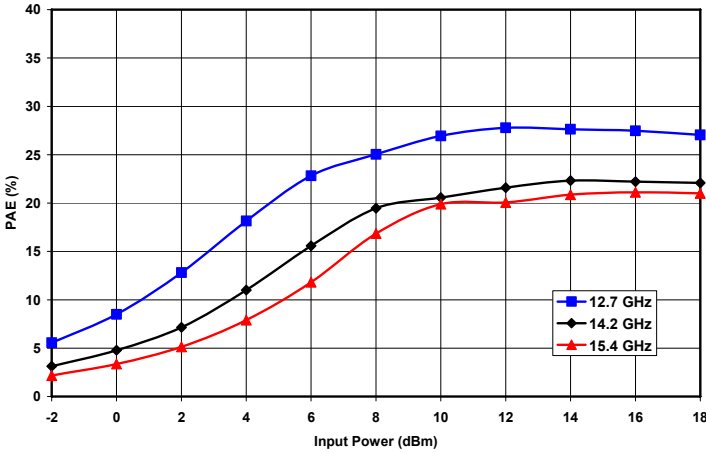


Figure 15. Power Added Efficiency vs. Input Power and Frequency at VD = 8V and IDQ = 210mA

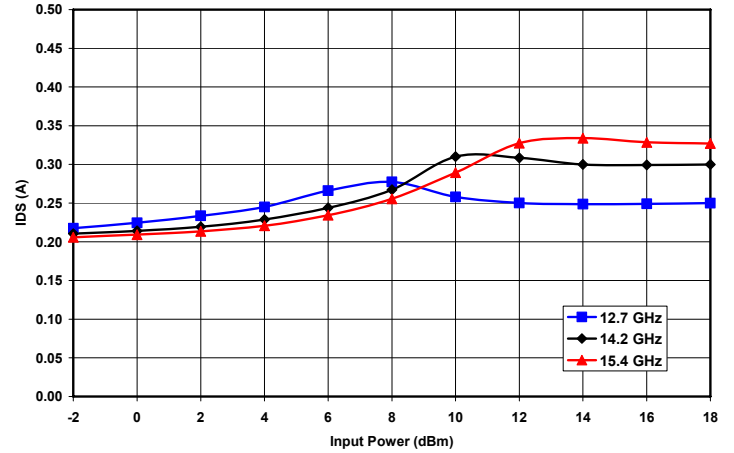


Figure 16. Drain Current vs. Input Power and Frequency at VD = 8V and IDQ = 210mA

VD = 10V

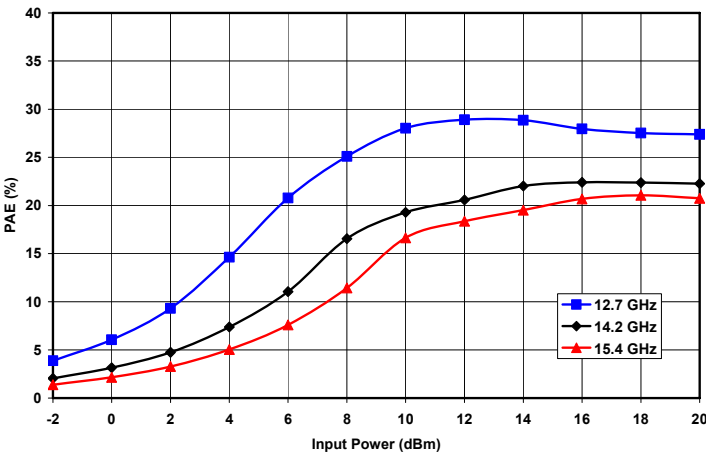


Figure 17. Power Added Efficiency vs. Input Power and Frequency at VD = 10V and IDQ = 210mA

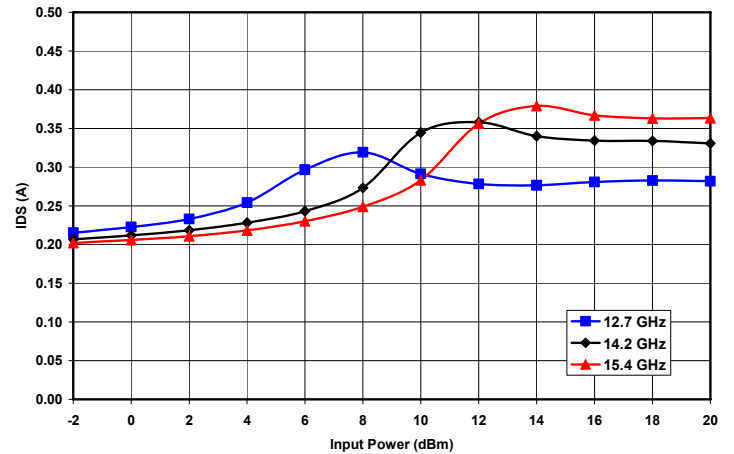


Figure 18. Drain Current vs. Input Power and Frequency at VD = 10V and IDQ = 210mA

**Amplifier, Power, 0.5W
12.7-15.4 GHz**

MAAP-000044-PKG003
Rev A
Preliminary Datasheet

VD = 6V

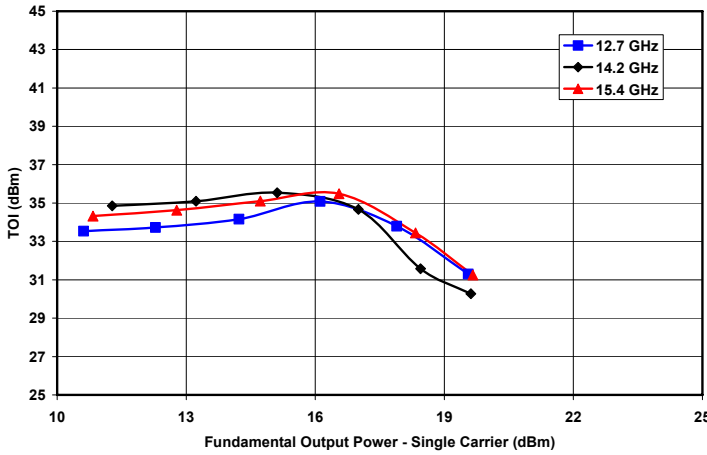


Figure 19. Third Order Intercept vs. Output Power and Frequency at VD = 6V and IDQ =210mA

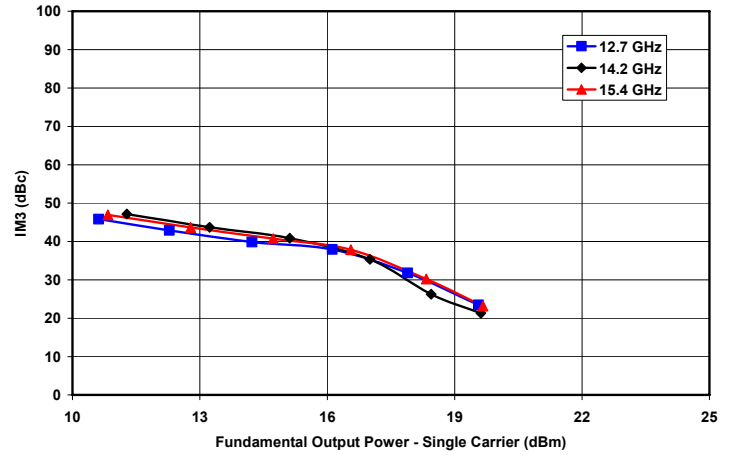


Figure 20. Third Order Intermod vs. Output Power and Frequency at VD = 6V and IDQ =210mA

VD = 8V

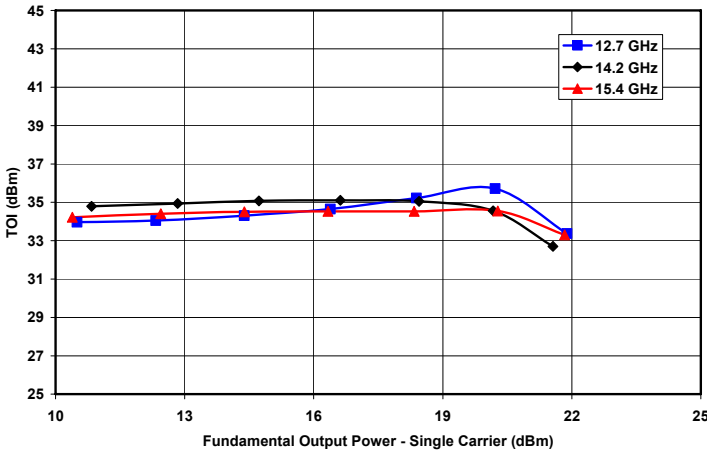


Figure 21. Third Order Intercept vs. Output Power and Frequency at VD = 8V and IDQ =210mA

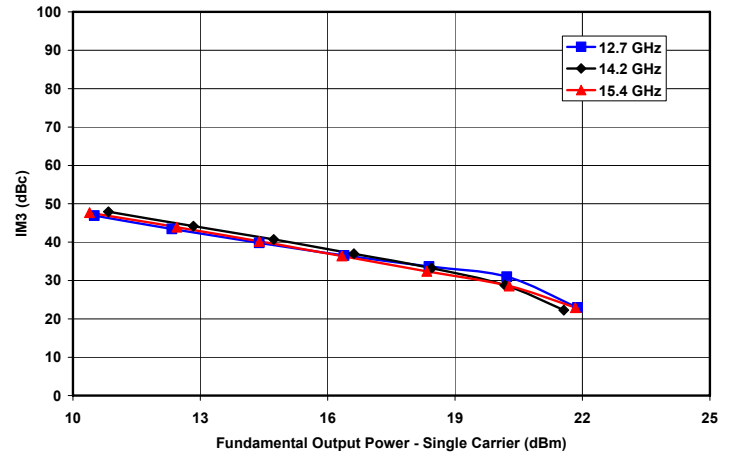


Figure 22. Third Order Intermod vs. Output Power and Frequency at VD = 8V and IDQ =210mA

VD = 10V

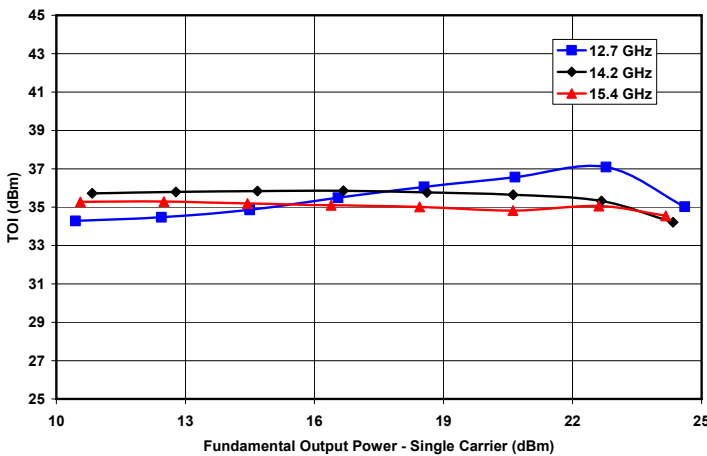


Figure 23. Third Order Intercept vs. Output Power and Frequency at VD = 10V and IDQ =210mA

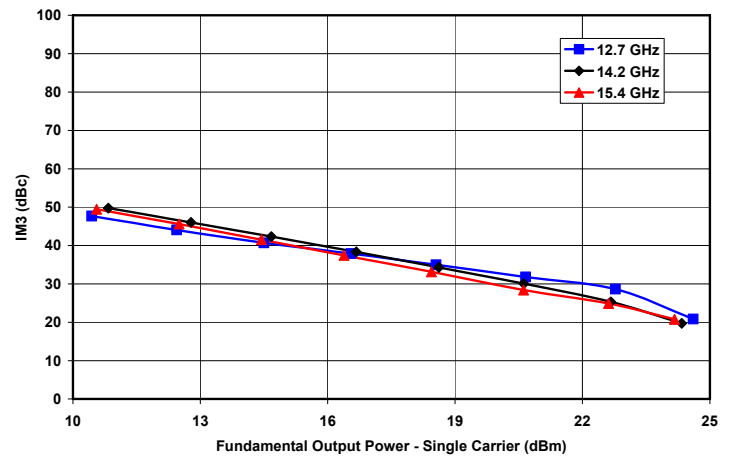


Figure 24. Third Order Intermod vs. Output Power and Frequency at VD = 10V and IDQ =210mA

**Amplifier, Power, 0.5W
12.7-15.4 GHz**

MAAP-000044-PKG003
Rev A
Preliminary Datasheet

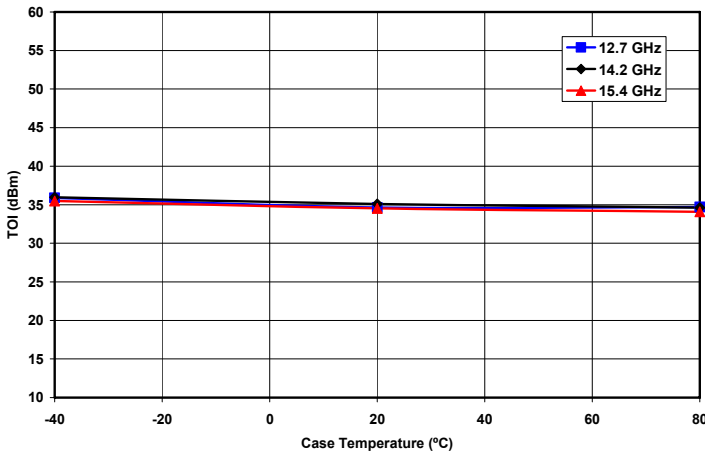


Figure 25. Third Order Intercept vs. Case Temperature and Frequency at Single Carrier Output Power Level = 16 dBm, VD = 8V and IDQ =210mA

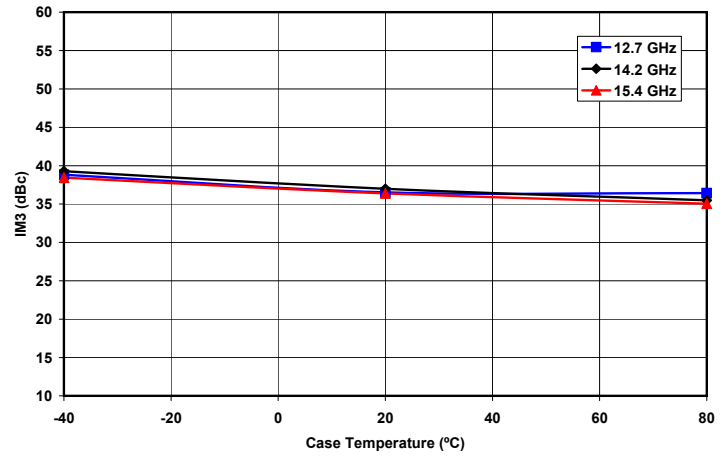


Figure 26. Third Order Intermod vs. Case Temperature and Frequency at Single Carrier Output Power Level = 16 dBm, VD = 8V and IDQ =210mA

**Amplifier, Power, 0.5W
12.7-15.4 GHz**

MAAP-000044-PKG003
Rev A
Preliminary Datasheet

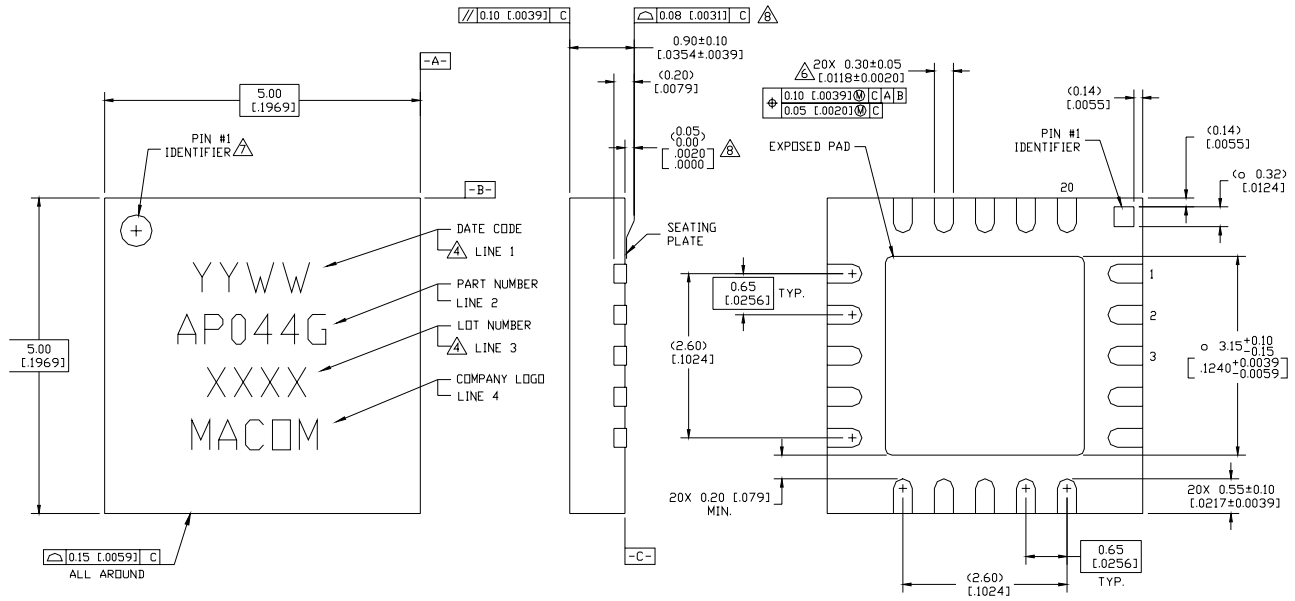


Figure 27. 5x5 mm 20-Lead MLP.

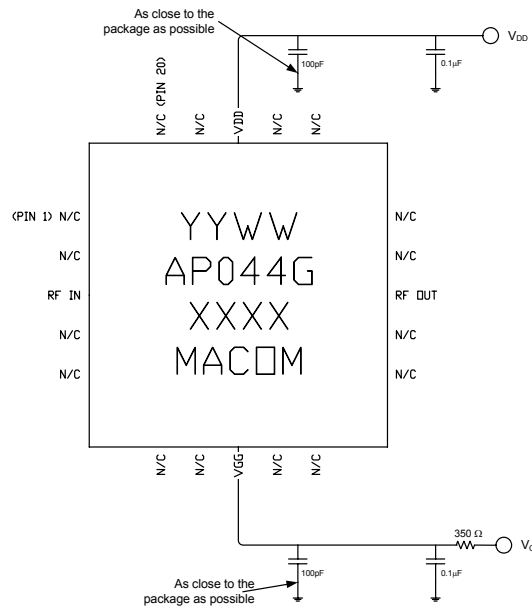


Figure 28. Recommended Bias Configuration.

Note: The exposed pad centered on the package bottom must be connected to RF and dc ground for proper electrical and thermal operation.

Refer to M/A-COM Application Note **Surface Mounting Instructions for PQFN Packages #S2083*** for assembly guidelines.

Additional Precaution: All parts must receive a bake-out of 125°C for 24 hours prior to any solder reflow operation.

*Application Notes can be found by going to the Site Search Page of M/A-COM's web page (<http://www.macom.com/search/search.jsp>) and searching for the required Application Note.

Amplifier, Power, 0.5W
12.7-15.4 GHz

MAAP-000044-PKG003
Rev A
Preliminary Datasheet

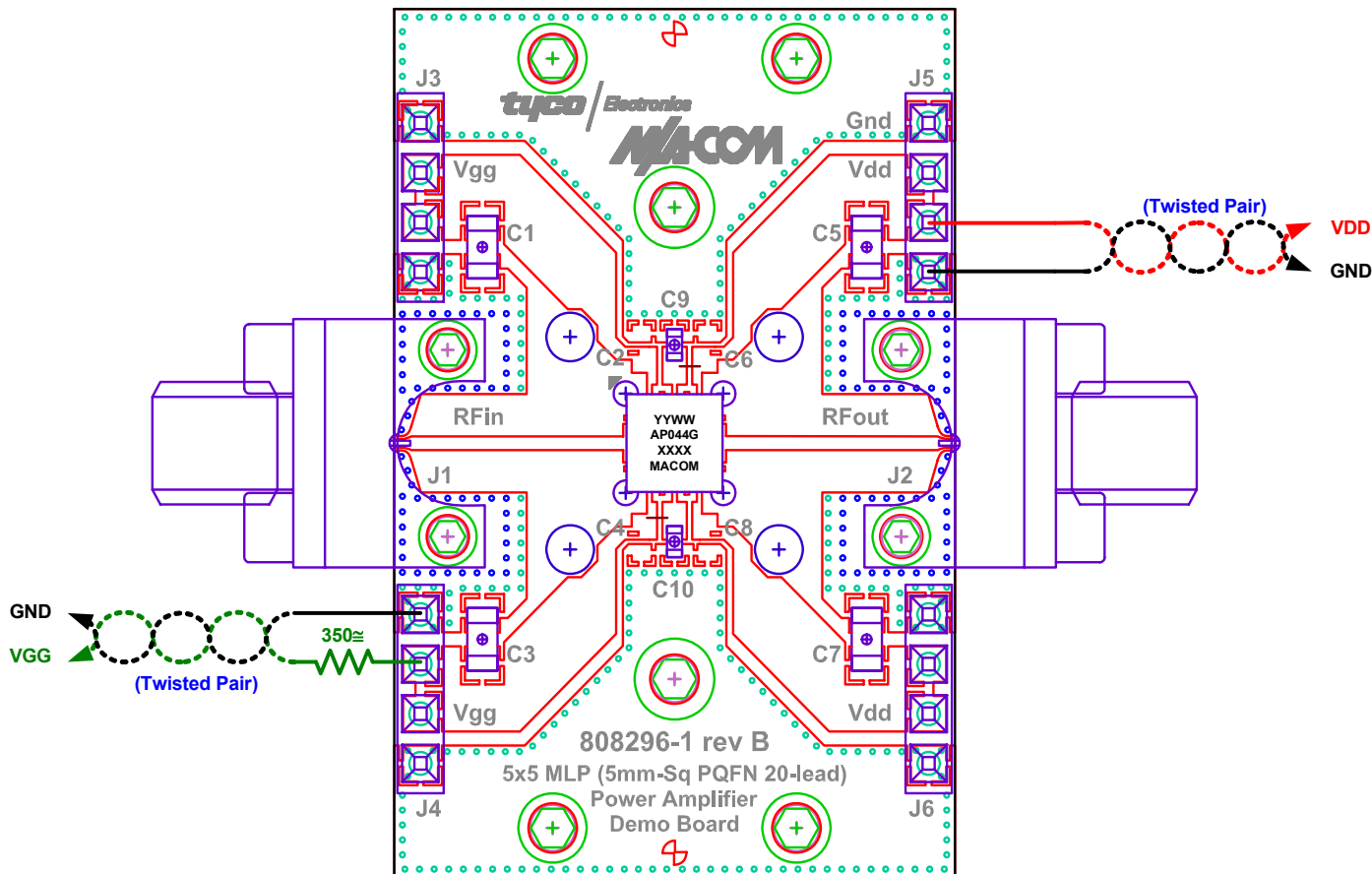


Figure 29. Demonstration Board PN MAAP-000044-SMB003 (available upon request).